April 2016

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#### 25V NPN SMALL SIGNAL TRANSISTOR IN SOT23

#### **Features**

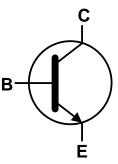
- BV<sub>CEO</sub> > 25V
- I<sub>C</sub> = 200mA High Collector Current
- Complementary PNP Type: MMBT4126
- Ideal for Medium Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

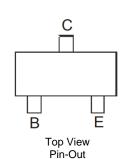
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
   Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)











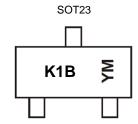
#### **Ordering Information** (Note 4)

Ē							
	Product	Status	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	MMBT4124-7-F	Active	AEC-Q101	K1B	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



K1N = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M or  $\overline{M}$  = Month (ex: 9 = September)

#### Date Code Key

Year	2014		2015	2016	;	2017	2018		2019	2020		2021
Code	В		С	D		Е	F		G	Н		ı
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	30	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	Ic	200	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	D	310	mW
Power Dissipation	(Note 6)	P <sub>D</sub>	350	IIIVV
Thermal Desistance, Junction to Ambient	(Note 5)	В	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	357	T
Thermal Resistance, Junction to Leads	(Note 7)	$R_{ heta JL}$	350	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

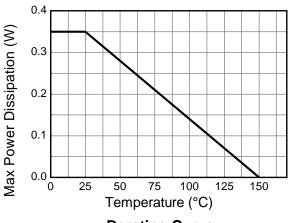
Notes:

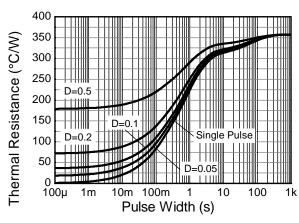
- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

  6. Same as Note 5, except the device is mounted on 15 mm x 15mm 1oz copper.
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



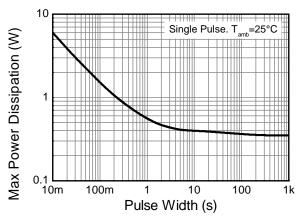
# **Thermal Characteristics and Derating Information**





**Derating Curve** 

**Transient Thermal Impedance** 



**Pulse Power Dissipation** 



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	$BV_{CBO}$	30	-	V	$I_{C} = 10\mu A, I_{E} = 0$	
Collector-Emitter Breakdown Voltage (Note 9)	$BV_{CEO}$	25	-	V	$I_C = 1.0 \text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage	$BV_{EBO}$	5.0	-	V	$I_E = 10\mu A, I_C = 0$	
Collector-Base Cut-off Current	I <sub>CBO</sub>	-	50	nA	$V_{CB}=20V, I_{E}=0$	
Emitter Base Cut-off Current	I <sub>EBO</sub>	-	50	nA	$V_{EB}=3.0V, I_{C}=0$	
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h <sub>FE</sub>	120	360	İ	$I_{C} = 2mA, V_{CE} = 1.0V$	
DC Current Gain		60	-		$I_C = 50 \text{mA}, V_{CE} = 1.0 \text{V}$	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	-	0.30	٧	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	=	0.95	V	$I_C = 50 \text{mA}, I_B = 5.0 \text{mA}$	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	$C_{obo}$	=	4.0	pF	$V_{CB} = 5.0V$ , $f = 1.0MHz$ , $I_E = 0$	
Input Capacitance	$C_{ibo}$	=	8.0	рF	$V_{EB} = 0.5V$ , $f = 1.0MHz$ , $I_{C} = 0$	
Small Signal Current Gain	h <sub>fe</sub>	120	480	ı	$V_{CE} = 1.0V, I_{C} = 2.0mA,$ f = 1.0kHz	
Current Gain-Bandwidth Product	f⊤	300	-	MHz	$V_{CE} = 20V, I_{C} = 10mA,$ f = 100MHz	

Note:

9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

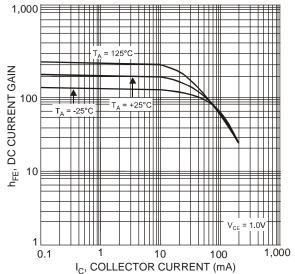
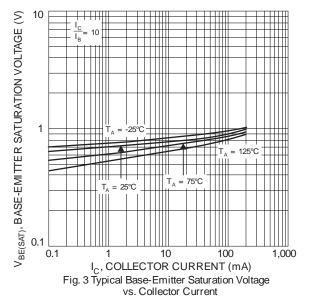


Fig. 1 Typical DC Current Gain vs. Collector Current



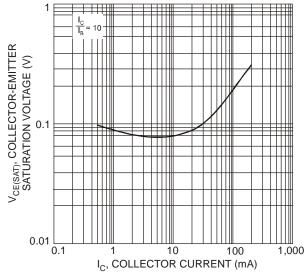


Fig. 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

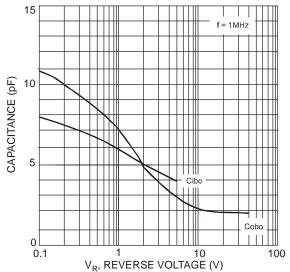
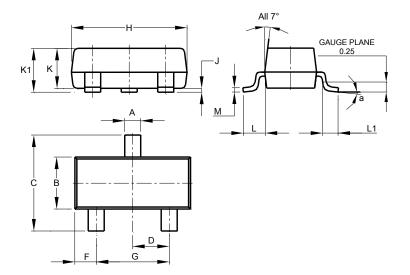


Fig. 4 Typical Capacitance Characteristics



### **Package Outline Dimensions**

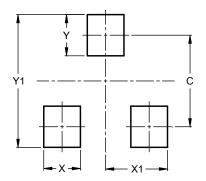
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
M	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	29



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